

## DDR 400 QVL for ASUS P4P800-E Deluxe Motherboard

(For optimum performance and overclocking stability)

Size	Vendor	Model	Brand		Component	A*	B*	C*
256MB	Apacer	77.10636.465	SAMSUNG	SS	K4H560838D-TCC4	V	V	V
512MB	Apacer	77.10636.11G	Hynix	DS	HYB25D256800BT-5B	V	V	
256MB	Transcend	TS32MLD64V4F3	SAMSUNG	SS	K4H560838E-TCC4	V	V	V
256MB	Transcend	TS32MLD64V4F3	MOSEL	SS	V58C2256804SAT5B	V	V	V
256MB	Transcend	TS32MLD64V4F3	SAMSUNG	SS	K4H560838D-TCCC	V	V	V
512MB	Transcend	TS64MLD64V4F3	Mosel	DS	V58C2256804SAT5B	V	V	V
256MB	A DATA	MDGAD5F3G315B1EC2	ADATA	SS	ADD8608A8A-5B	V	V	
256MB	A DATA	MDOAD5F3G31YB1EZ2	ADATA	SS	ADD8608A8A-5B	V	V	V
256MB	A DATA	MDOWB5F3G316B1EAE	Winbond	SS	W942508BH-5	V	V	
256MB	A DATA	MDOSS6F3G31YK1EZZ	SAMSUNG	SS	K4H560838E-TCCC	V	V	V
256MB	MICRON	MT8VDDT3264AG-40BC4	MICRON	SS	MT46V32M8TG-5BC	V		
512MB	MICRON	MT16VDDT6464AG-40BC4	MICRON	DS	MT46V32M8TG-5BC	V		
512MB	MICRON	MT16VDDT6464AG-40BCB	MICRON	DS	MT46V32M8TG-5BC	V	V	
128MB	Infineon	HYS64D16301GU-5-B	Infineon	SS	HYB25D256160BT-5B	V	V	V
256MB	Infineon	HYS64D32300GU-5-B	Infineon	SS	HYB25D256800BT-5B	V		
512MB	Infineon	HYS64D32300HU-5-B	Infineon	DS	HYB25D256800CE-5B	V	V	
256MB	Infineon	HYS64D32300HU-5-C	Infineon	DS	HYB25D256800CE-5C	V	V	
256MB	Winbond	W9425GCDB-5	Winbond	SS	W942508CH-5	V	V	
512MB	Winbond	W9451GCDB-5	Winbond	DS	W942508CH-5	V	V	V
256MB	SAMSUNG	M368L3223ETM-CCC	SAMSUNG	SS	K4H560838E-TCCC	V	V	
256MB	SAMSUNG	M368L3223FTM-CCC	SAMSUNG	SS	K4H560838F-TCCC	V	V	
512MB	SAMSUNG	M368L6423FTM-CCC	SAMSUNG	DS	K4H560838F-TCCC	V	V	V
256MB	TwinMOS	M2G9I08AFATT9F081AA4T	TwinMOS	SS	TMD7608F8E50D	V	V	
512MB	TwinMOS	M2G9J16AGATT9F081AA4T	TwinMOS	DS	TMD7608F8E50D	V	V	V

256MB	TwinMOS	M2S9I08AFAPS9F0811A-T	PSC	SS	A2S56D30ATP	V	V	V
256MB	Hynix	HYMD232646B8J-D43 AA	Hynix	SS	HY5DU56822BT-D43	V	V	
512MB	Corsair	VS512MB400	VALUE SELECT	DS	VS32M8-5	V	V	V
512MB	Corsair	XMS3200/CMX512-3200C2	N/A	DS	N/A	V	V	V
256MB	ATP	AG32L64T8SQC4S	SAMSUNG	SS	K4H560838D-TCC4	V		
512MB	ATP	AG64L64T8SQC4S	SAMSUNG	DS	K4H560838D-TCC4	V	V	
256MB	CENTURY	DXV6S8SSCCD3K27C	SAMSUNG	SS	K4H560838D-TCCC	V	V	V
512MB	CENTURY	DXV2S8SSCCD3K27C	SAMSUNG	DS	K4H560838D-TCCC	V	V	V
256MB	Kingston	KVR400X64C3A/256	hynix	SS	HY5DU56822BT-D43	V	V	
512MB	Kingston	KVR400X64C3A/512	hynix	DS	HY5DU56822BT-D43	V	V	V
256MB	KINGMAX	MPXB62D-38KT3R	KINGMAX	SS	KDL388P4EA-50	V	V	V
512MB	KINGMAX	MPXC22D-38KT3R	KINGMAX	DS	KDL388P4EA-50(A)	V	V	
512MB	KINGMAX	MPXC22D-38KT3R	Mosel	DS	V58C2256804SAT5B	V	V	V
256MB	KINGMAX	MPXB62D-38LT3R	Mosel	SS	V58C2256804SAT5B	V	V	
128MB	NANYA	NT128D64SH4B1G-5T	NANYA	SS	NT5DS16M16BT-5T	V	V	V
512MB	NANYA	NT512D64S8HB1G-5T	NANYA	DS	NT5DS32M8BT-5T	V	V	V
256MB	elixir	M2U25664DS88B3G-5T	elixir	SS	N2DS25680BT-5T	V	V	V
512MB	elixir	M2U51264DS88B3G-5T	elixir	DS	N2DS25680BT-5T	V	V	V
256MB	Kreton	N/A	Kreton	SS	VT3225804T-5	V	V	V
512MB	Kreton	N/A	Kreton	DS	VT3225804T-5	V	V	V
256MB	Veritech	VT400FMV/2561103	Veritech	SS	VT56DD32M8PC-5	V	V	V
512MB	GEIL	GD3200-512V	N/A	DS	WLCSP Package	V	V	V
512MB	TwinMOS	M2G9II6AJATT9F0811DDT	TwinMOS	DS	TMD7608F8E50B	V	V	V
256MB	TwinMOS	M2G9I08AFTT9F0811DDT	TwinMOS	SS	TMD7608F8E50B	V	V	
256MB	TwinMOS	M2G9I08AFATT9F081AA4T	TwinMOS	SS	TMD7608F8E50D	V	V	V
256MB	TwinMOS	M2S9I08AFAPS9F0811A-T	TwinMOS	SS	A2S56D30ATP	V	V	V
512MB	Apacer	77.10636.18G	Hynix	DS	HYB25D256809BT-5B	V	V	V
256MB	Apacer	77.10636.11G	Hynix	SS	HYB25D256800BT-5B	V	V	V
512MB	KINGMAX	MPXC22D-38LT3R	Mosel	DS	V58C2256804SAT5B	V	V	V
512MB	Transcend	N/A	SAMSUNG	DS	K4H560838E-TCCC	V	V	

256MB	GEIL	GE2563200B	GEIL	SS	GL3LC32G88TG-5A	V	V	
512MB	GEIL	GE5123200B	GEIL	DS	GL3LC32G88TG-5A	V	V	
256MB	GEIL	GD3200-256V	N/A	SS	WLCSP Package	V	V	V
256MB	Kingston	KVR400X64C25/256	Winbond	SS	W942508BH-5	V	V	
512MB	Kingston	KVR400X64C3A/512	Winbond	DS	D328DIB-50	V	V	
512MB	Infineon	HYS64D64320GU-5-B	Infineon	DS	HYB25D256800BT-5B	V	V	
256MB	SAMSUNG	M368L3223FTN-CCC	SAMSUNG	SS	K4H560838F-TCCC	V	V	
512MB	SAMSUNG	M368L6423FTN-CCC	SAMSUNG	DS	K4H560838F-TCCC	V	V	
256MB	PSC	AL5D8B53T-5B1K	PSC	SS	A2S56D30BTP	V	V	V
512MB	PSC	AL6D8B53T-5B1K	PSC	DS	A2S56D30BTP	V	V	V
1024MB	ATP	AG28L64T8SMC4M	N/A	DS	MT46V64M4TG-5BC	V		
256MB	Brain Power	B6U808-256M-SAM-400	SAMSUNG	SS	K4H560838D-TCC4	V	V	
512MB	Brain Power	B6U808-512M-SAM-400	SAMSUNG	DS	K4H560838D-TCC4	V	V	V
256MB	CENTURY	DXV6S8MC5BC3U27E	N/A	SS	MT46V32M8TG-5BC	V	V	V
512MB	CENTURY	DXV2S8MC5BC3U27E	N/A	DS	MT46V32M8TG-5BC	V	V	V

A\* : Supports one module inserted in any slot as Single-channel memory configuration

B\* : Supports one pair of modules inserted into either the blue slots or the black slots as one pair of Dual-channel memory configuration

C\* : Supports 4 modules inserted into both the blue and black slots as two pairs of Dual-channel memory configuration